74HC03; 74HCT03 Quad 2-input NAND gate; open-drain output Rev. 4 — 27 November 2015

Product data sheet

#### **General description** 1.

The 74HC03; 74HCT03 is a quad 2-input NAND gate with open-drain outputs. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

#### **Features and benefits** 2.

- Input levels:
  - For 74HC03: CMOS level
  - For 74HCT03: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

#### **Ordering information** 3.

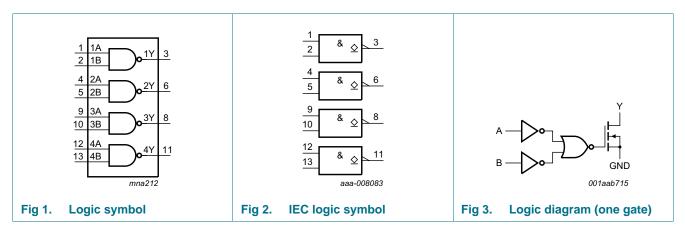
#### Table 1. **Ordering information**

| Type number | Package           |         |  |          |  |  |  |  |  |  |
|-------------|-------------------|---------|--|----------|--|--|--|--|--|--|
|             | Temperature range | Name    | Description  | Version  |  |  |  |  |  |  |
| 74HC03D     | –40 °C to +125 °C | SO14    | plastic small outline package; 14 leads; body width  | SOT108-1 |  |  |  |  |  |  |
| 74HCT03D    |                   |         | 3.9 mm   |          |  |  |  |  |  |  |
| 74HC03DB    | –40 °C to +125 °C | SSOP14  | plastic shrink small outline package; 14 leads; body | SOT337-1 |  |  |  |  |  |  |
| 74HCT03DB   |                   |         | width 5.3 mm   |          |  |  |  |  |  |  |
| 74HC03PW    | –40 °C to +125 °C | TSSOP14 | plastic thin shrink small outline package; 14 leads; | SOT402-1 |  |  |  |  |  |  |
| 74HCT03PW   |                   |         | body width 4.4 mm                                    |          |  |  |  |  |  |  |



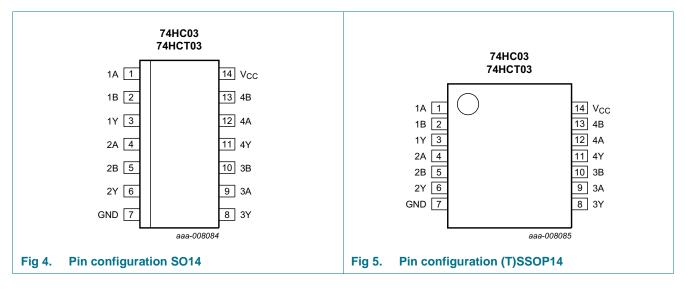
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## 4. Functional diagram



# 5. Pinning information

## 5.1 Pinning



## 5.2 Pin description

| Table 2. Pin description |              |                |
|--------------------------|--------------|----------------|
| Symbol                   | Pin          | Description    |
| 1A to 4A                 | 1, 4, 9, 12  | data input     |
| 1B to 4B                 | 2, 5, 10, 13 | data input     |
| 1Y to 4Y                 | 3, 6, 8, 11  | data output    |
| GND                      | 7            | ground (0 V)   |
| V <sub>cc</sub>          | 14           | supply voltage |

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## 6. Functional description

| Table 3. F | unction | table <sup>[1]</sup> |
|------------|---------|----------------------|
|------------|---------|----------------------|

| Input | Output |    |
|-------|--------|----|
| nA    | nB     | nY |
| L     | L      | Z  |
| L     | Н      | Z  |
| Н     | L      | Z  |
| Н     | Н      | L  |

[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

## 7. Limiting values

### Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                   | Conditions   |            | Min  | Max  | Unit |
|------------------|-----------------------------|--|------------|------|------|------|
| V <sub>CC</sub>  | supply voltage              |  |            | -0.5 | +7   | V    |
| Vo               | output voltage              |  | <u>[1]</u> | -0.5 | +7   | V    |
| I <sub>IK</sub>  | input clamping current      | $V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V | <u>[1]</u> | -    | ±20  | mA   |
| Ι <sub>ΟΚ</sub>  | output clamping current     | V <sub>O</sub> < -0.5 V                                  | <u>[1]</u> | -    | -20  | mA   |
| I <sub>O</sub>   | output current              | -0.5 V < V <sub>O</sub>                                  |            | -    | -25  | mA   |
| I <sub>CC</sub>  | supply current              |  |            | -    | 50   | mA   |
| I <sub>GND</sub> | ground current              |  |            | -50  | -    | mA   |
| T <sub>stg</sub> | storage temperature         |  |            | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation     |  | [2]        |      |      |      |
|                  | SO14 and (T)SSOP14 packages |  |            | -    | 500  | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO14 package: Ptot derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

## 8. Recommended operating conditions

### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

| Symbol                | Parameter                           | Conditions       |     | 74HC03 |                 |     | 74HCT03 |                 |      |
|-----------------------|-------------------------------------|------------------|-----|--------|-----------------|-----|---------|-----------------|------|
|                       |                                     |                  | Min | Тур    | Max             | Min | Тур     | Max             |      |
| V <sub>CC</sub>       | supply voltage                      |                  | 2.0 | 5.0    | 6.0             | 4.5 | 5.0     | 5.5             | V    |
| VI                    | input voltage                       |                  | 0   | -      | V <sub>CC</sub> | 0   | -       | V <sub>CC</sub> | V    |
| Vo                    | output voltage                      |                  | 0   | -      | V <sub>CC</sub> | 0   | -       | V <sub>CC</sub> | V    |
| T <sub>amb</sub>      | ambient temperature                 |                  | -40 | +25    | +125            | -40 | +25     | +125            | °C   |
| $\Delta t / \Delta V$ | input transition rise and fall rate | $V_{CC} = 2.0 V$ | -   | -      | 625             | -   | -       | -               | ns/V |
|                       |                                     | $V_{CC} = 4.5 V$ | -   | 1.67   | 139             | -   | 1.67    | 139             | ns/V |
|                       |                                     | $V_{CC} = 6.0 V$ | -   | -      | 83              | -   | -       | -               | ns/V |

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# 9. Static characteristics

### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                   | Conditions  |      | 25 °C |      | <b>−40 °C t</b> | o +85 °C | –40 °C to +125 °C |      | Unit |
|-----------------|-----------------------------|---|------|-------|------|-----------------|----------|-------------------|------|------|
|                 |                             |   | Min  | Тур   | Max  | Min             | Max      | Min               | Max  |      |
| 74HC03          |                             |   |      |       |      |                 |          |                   |      |      |
| V <sub>IH</sub> | HIGH-level                  | V <sub>CC</sub> = 2.0 V   | 1.5  | 1.2   | -    | 1.5             | -        | 1.5               | -    | V    |
|                 | input voltage               | V <sub>CC</sub> = 4.5 V   | 3.15 | 2.4   | -    | 3.15            | -        | 3.15              | -    | V    |
|                 |                             | V <sub>CC</sub> = 6.0 V   | 4.2  | 3.2   | -    | 4.2             | -        | 4.2               | -    | V    |
| V <sub>IL</sub> | LOW-level                   | V <sub>CC</sub> = 2.0 V   | -    | 0.8   | 0.5  | -               | 0.5      | -                 | 0.5  | V    |
|                 | input voltage               | V <sub>CC</sub> = 4.5 V   | -    | 2.1   | 1.35 | -               | 1.35     | -                 | 1.35 | V    |
|                 |                             | V <sub>CC</sub> = 6.0 V   | -    | 2.8   | 1.8  | -               | 1.8      | -                 | 1.8  | V    |
| V <sub>OL</sub> | LOW-level                   | $V_{I} = V_{IH} \text{ or } V_{IL}$   |      |       |      |                 |          |                   |      |      |
|                 | output voltage              | $I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$  | -    | 0     | 0.1  | -               | 0.1      | -                 | 0.1  | V    |
|                 |                             | $I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 4.5 V  | -    | 0     | 0.1  | -               | 0.1      | -                 | 0.1  | V    |
|                 |                             | $I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$  | -    | 0     | 0.1  | -               | 0.1      | -                 | 0.1  | V    |
|                 |                             | $I_{O}$ = 4.0 mA; $V_{CC}$ = 4.5 V  | -    | 0.15  | 0.26 | -               | 0.33     | -                 | 0.4  | V    |
|                 |                             | $I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$  | -    | 0.16  | 0.26 | -               | 0.33     | -                 | 0.4  | V    |
| I               | input leakage current       | $V_I = V_{CC}$ or GND;<br>$V_{CC} = 6.0 V$  | -    | 0.1   | -    | -               | ±1       | -                 | ±1   | μA   |
| I <sub>OZ</sub> | OFF-state<br>output current | per input pin; $V_I = V_{IL}$ ;<br>$V_O = V_{CC}$ or GND;<br>other inputs at $V_{CC}$ or GND;<br>$V_{CC} = 6.0 \text{ V}$ ; $I_O = 0 \text{ A}$ | -    | -     | ±0.5 | -               | ±5.0     | -                 | ±10  | μA   |
| I <sub>CC</sub> | supply current              |   | -    | 2.0   | -    | -               | 20       | -                 | 40   | μA   |
| CI              | input<br>capacitance        |   | -    | 3.5   | -    | -               | -        | -                 | -    | pF   |
| 74HCT0          | 3                           |   | 1    |       |      | 1               | 1        | 1                 |      |      |
| V <sub>IH</sub> | HIGH-level<br>input voltage | $V_{CC}$ = 4.5 V to 5.5 V   | 2.0  | 1.6   | -    | 2.0             | -        | 2.0               | -    | V    |
| V <sub>IL</sub> | LOW-level input voltage     | $V_{CC}$ = 4.5 V to 5.5 V   | -    | 1.2   | 0.8  | -               | 0.8      | -                 | 0.8  | V    |
| V <sub>OL</sub> | LOW-level                   | $V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$   |      |       |      |                 |          |                   |      |      |
|                 | output voltage              | I <sub>O</sub> = 20 μA  | -    | 0     | 0.1  | -               | 0.1      | -                 | 0.1  | V    |
|                 |                             | I <sub>O</sub> = 4.0 mA   | -    | 0.15  | 0.26 | -               | 0.33     | -                 | 0.4  | V    |
| I               | input leakage current       | $V_I = V_{CC}$ or GND;<br>$V_{CC} = 5.5 V$  | -    | -     | ±0.1 | -               | ±1       | -                 | ±1   | μA   |
| loz             | OFF-state<br>output current | per input pin; $V_I = V_{IL}$ ;<br>$V_O = V_{CC}$ or GND;<br>other inputs at $V_{CC}$ or GND;<br>$V_{CC} = 5.5$ V; $I_O = 0$ A                  | -    | -     | ±0.5 | -               | ±5.0     | -                 | ±10  | μA   |

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## Quad 2-input NAND gate; open-drain output

### Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol Parameter |                           | Conditions  | 25 °C |     | –40 °C to +85 °C |     | –40 °C to +125 °C |     | Unit |    |
|------------------|---------------------------|---|-------|-----|------------------|-----|-------------------|-----|------|----|
|                  |                           |   | Min   | Тур | Max              | Min | Max               | Min | Max  |    |
| I <sub>CC</sub>  | supply current            |   | -     | -   | 2.0              | -   | 20                | -   | 40   | μA |
| ΔI <sub>CC</sub> | additional supply current | per input pin;<br>$V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$<br>other inputs at $V_{CC}$ or GND;<br>$V_{CC} = 4.5 \text{ V}$ to 5.5 V | -     | 100 | 360              | -   | 450               | -   | 490  | μA |
| CI               | input<br>capacitance      |   | -     | 3.5 | -                | -   | -                 | -   | -    | pF |

## **10. Dynamic characteristics**

### Table 7. Dynamic characteristics

GND = 0 V;  $C_L = 50$  pF; for test circuit, see <u>Figure 7</u>.

| Symbol                           | Parameter                     | Conditions  |            |   | 25 °C |     | -40 °C to      | o +125 ℃        | Unit |
|----------------------------------|-------------------------------|---|------------|---|-------|-----|----------------|-----------------|------|
|                                  |                               |   | _          |   | Тур   | Max | Max<br>(85 °C) | Max<br>(125 °C) |      |
| 74HC03                           |                               |   |            |   |       |     |                |                 |      |
| t <sub>pd</sub> propagation dela | nA, nB to nY; see Figure 6    | <u>[1]</u>  |            |   |       |     |                |                 |      |
|                                  |                               | V <sub>CC</sub> = 2.0 V                                 |            | - | 28    | 95  | 120            | 145             | ns   |
|                                  |                               | V <sub>CC</sub> = 4.5 V                                 |            | - | 10    | 19  | 24             | 29              | ns   |
|                                  |                               | $V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$ |            | - | 8     | -   | -              | -               | ns   |
|                                  |                               | $V_{CC} = 6.0 V$  |            | - | 8     | 16  | 20             | 25              | ns   |
| t <sub>t</sub>                   | transition time               | see <u>Figure 6</u>                                     | [2]        |   |       |     |                |                 |      |
|                                  |                               | $V_{CC} = 2.0 V$  |            | - | 19    | 75  | 95             | 110             | ns   |
|                                  |                               | V <sub>CC</sub> = 4.5 V                                 |            | - | 7     | 15  | 19             | 22              | ns   |
|                                  |                               | $V_{CC} = 6.0 V$  |            | - | 6     | 13  | 16             | 19              | ns   |
| C <sub>PD</sub>                  | power dissipation capacitance | per package; $V_I = GND$ to $V_{CC}$                    | <u>[3]</u> | - | 4     | -   | -              | -               | pF   |

### Quad 2-input NAND gate; open-drain output

| Symbol                            | Parameter                     | Conditions  |            | 25 °C |     |                | -40 °C to       | o +125 ℃ | Unit |
|-----------------------------------|-------------------------------|---|------------|-------|-----|----------------|-----------------|----------|------|
|                                   |                               |   | Min        | Тур   | Мах | Max<br>(85 °C) | Max<br>(125 °C) |          |      |
| 74HCT03                           | 3                             | 1   |            |       |     |                |                 |          |      |
| t <sub>pd</sub> propagation delay | propagation delay             | nA, nB to nY; see Figure 6                                      | <u>[1]</u> |       |     |                |                 |          |      |
|                                   |                               | V <sub>CC</sub> = 4.5 V   |            | -     | 12  | 24             | 30              | 36       | ns   |
|                                   |                               | V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF                 |            | -     | 10  | -              | -               | -        | ns   |
| t <sub>t</sub>                    | transition time               | V <sub>CC</sub> = 4.5 V; see <u>Figure 6</u>                    | [2]        | -     | 7   | 15             | 19              | 22       | ns   |
| C <sub>PD</sub>                   | power dissipation capacitance | per package;<br>V <sub>I</sub> = GND to V <sub>CC</sub> – 1.5 V | <u>[3]</u> | -     | 4   | -              | -               | -        | pF   |

#### Table 7. Dynamic characteristics ... continued $GND = 0 V \cdot C_{i}$ = 50 pF; for test circuit, see Figure 7

[1]  $t_{pd}$  is the same as  $t_{PLZ}$  and  $t_{PZL}$ .

[2]  $t_t$  is the same as  $t_{THL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

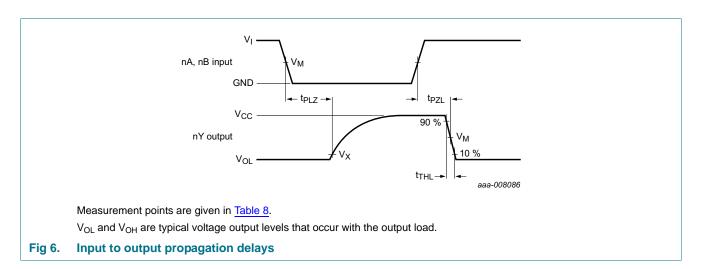
 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

## 11. Waveforms



#### Table 8. **Measurement points**

| Туре    | Input              | Output             |                    |  |  |
|---------|--------------------|--------------------|--------------------|--|--|
|         | V <sub>M</sub>     | V <sub>M</sub>     | V <sub>X</sub>     |  |  |
| 74HC03  | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> | 0.1V <sub>CC</sub> |  |  |
| 74HCT03 | 1.3 V              | 1.3 V              | 0.1V <sub>CC</sub> |  |  |

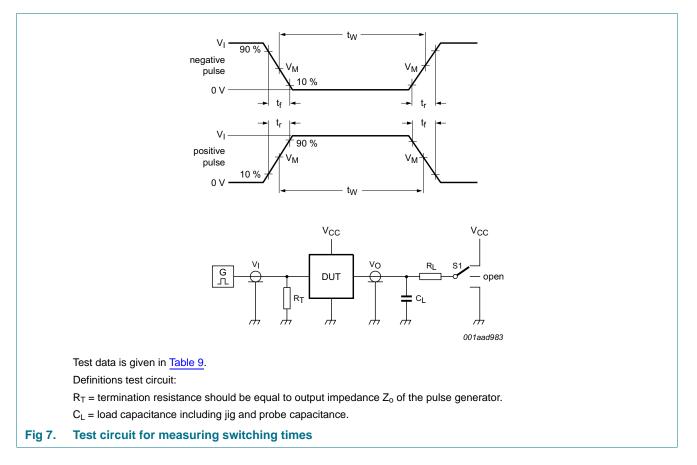
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## Quad 2-input NAND gate; open-drain output

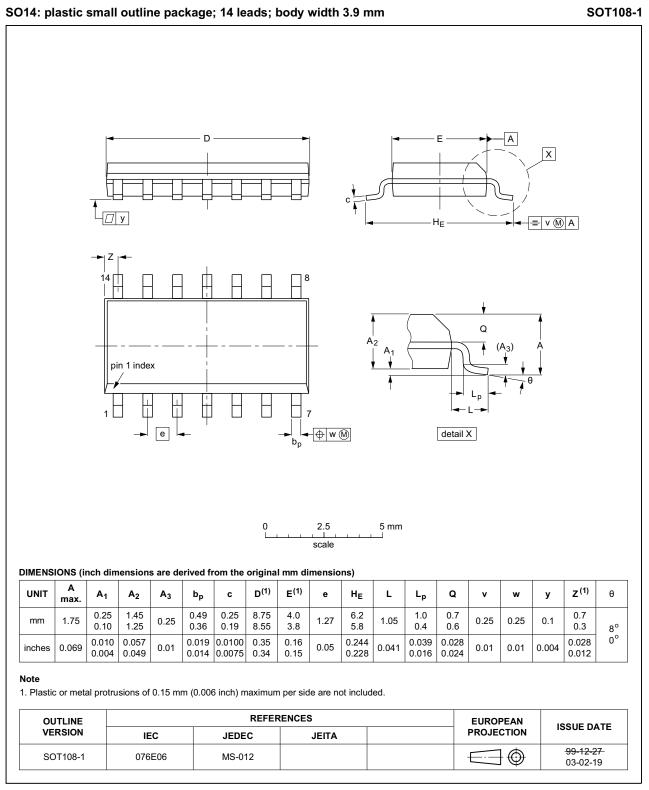


### Table 9. Test data

| Туре    | Input           |                                 | Load         | S1 position |                                     |
|---------|-----------------|---------------------------------|--------------|-------------|-------------------------------------|
|         | VI              | t <sub>r</sub> , t <sub>f</sub> | CL           | RL          | t <sub>PZL</sub> , t <sub>PLZ</sub> |
| 74HC03  | V <sub>CC</sub> | 6 ns                            | 15 pF, 50 pF | 1 kΩ        | V <sub>CC</sub>                     |
| 74HCT03 | 3.0 V           | 6 ns                            | 15 pF, 50 pF | 1 kΩ        | V <sub>CC</sub>                     |

Quad 2-input NAND gate; open-drain output

## 12. Package outline



### Fig 8. Package outline SOT108-1 (SO14)

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Quad 2-input NAND gate; open-drain output

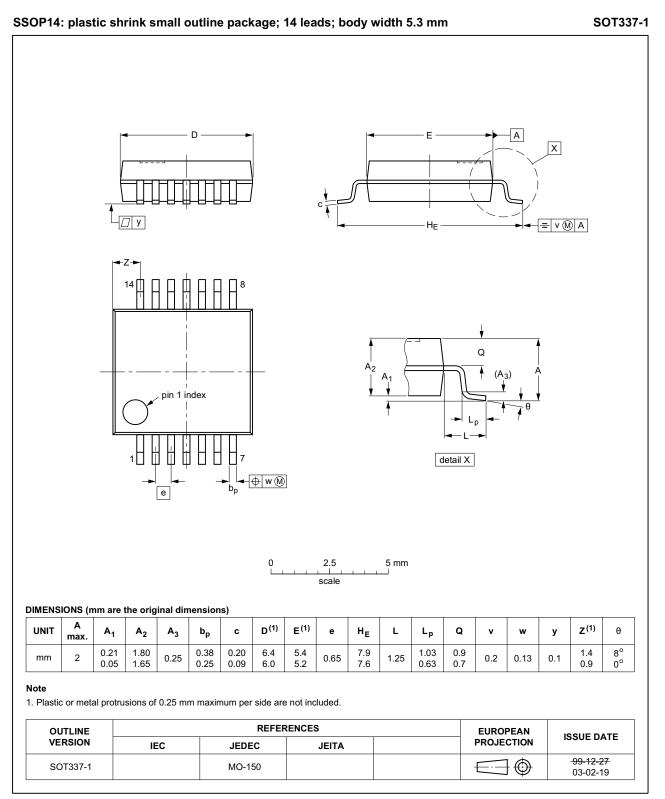


Fig 9. Package outline SOT337-1 (SSOP14)

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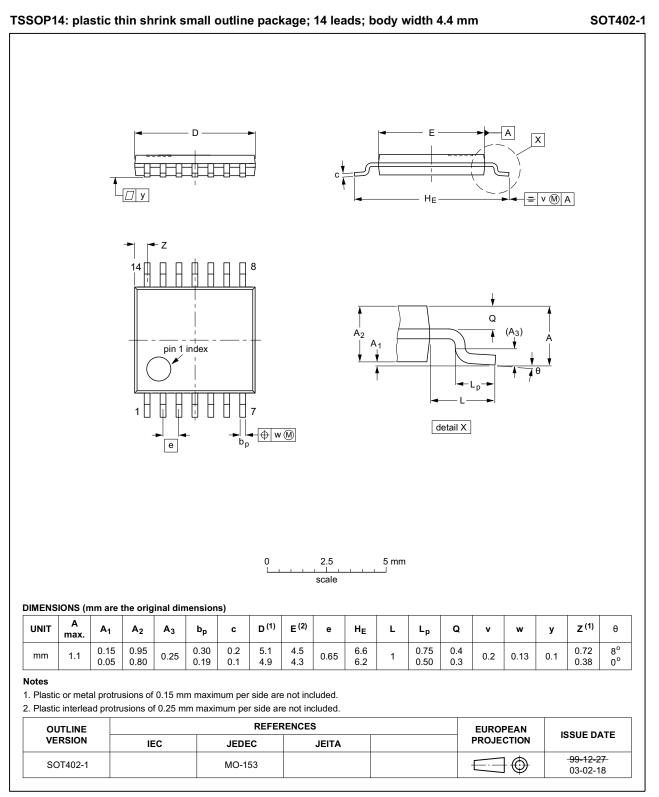


Fig 10. Package outline SOT402-1 (TSSOP14)

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Quad 2-input NAND gate; open-drain output

# **13. Abbreviations**

| Table 10. Abbreviations |   |  |  |
|-------------------------|---|--|--|
| Acronym                 | Description                             |  |  |
| CMOS                    | Complementary Metal-Oxide Semiconductor |  |  |
| DUT                     | Device Under Test                       |  |  |
| ESD                     | ElectroStatic Discharge                 |  |  |
| НВМ                     | Human Body Model                        |  |  |
| MM                      | Machine Model                           |  |  |
| TTL                     | Transistor-Transistor Logic             |  |  |

# 14. Revision history

### Table 11. Revision history

| Document ID        | Release date   | Data sheet status     | Change notice | Supersedes         |  |
|--------------------|--|-----------------------|---------------|--------------------|--|
| 74HC_HCT03 v.4     | 20151127   | Product data sheet    | -             | 74HC_HCT03 v.3     |  |
| Modifications:     | <ul> <li>Type numbers 74HC03N and 74HCT03N (SOT27-1) removed.</li> </ul>   |                       |               |                    |  |
| 74HC_HCT03 v.3     | 20130627   | Product data sheet    | -             | 74HC_HCT03_CNV v.2 |  |
| Modifications:     | <ul> <li>The format of this data sheet has been redesigned to comply with the new identity guideline<br/>of NXP Semiconductors.</li> </ul> |                       |               |                    |  |
|                    | <ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>   |                       |               |                    |  |
| 74HC_HCT03_CNV v.2 | 19970827   | Product specification | -             | -                  |  |

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## 15. Legal information

#### 15.1 Data sheet status

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet   | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions"

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Product data sheet

### Quad 2-input NAND gate; open-drain output

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